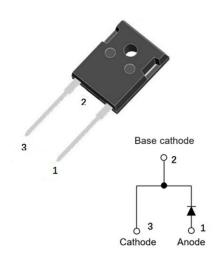






Silicon Carbide Schottky Diode

V_{RRM}	650V
I _{F (135°C)}	34A
Q _C	92nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

• Package: TO-247AC

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

• Terminals: Tin plated leads

• Polarity: As marked

■Maximum Ratings (T_C=25 °C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D106530NYG4
Reverse voltage (Repetitive peak) @ T _j =25°C	V_{RRM}	٧	650
Reverse voltage (Surge peak) @ T _j =25°C	V_{RSM}	V	650
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	650
Continuous forward current @ T _C =25°C		Α	75
Continuous forward current @ T _C =135°C	I _F		34
Continuous forward current @ T _C =142°C			30
Non-repetitive peak forward surge current @ T _C =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	200
Power Dissipation@ T _C =25°C	D	W	238
Power Dissipation@ T _C =110°C	Ртот		103
i²t Value@ T _C =25°C ,tp=10ms	∫ i²dt	A ² S	200
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175





■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V _F	V	I _F =30A, T _j =25°C	1.36	1.58
			I _F =30A, T _j =175°C	1.75	-
Reverse current	I _R	μA	V _R =650V, T _j =25°C	0.2	25
			V _R =650V, T _j =175°C	2	-
Total capacitive charge	Q _C	nC	V_R =400V, T_j =25°C, Q_C = $\int_0^{VR} C(V) dV$	92	-
	otal capacitance C	pF	V _R =0V, f=1MHZ	1732	-
Total capacitance			V _R =200V, f=1MHZ	171	-
			V _R =400V, f=1MHZ	164	-
Capacitance stored energy	Ec	μJ	V _R =400V	11	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{\theta J\text{-}C}$	°C W	0.63

■Typical Characteristics

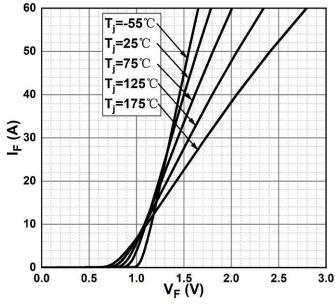


Figure 1. Forward Characteristics

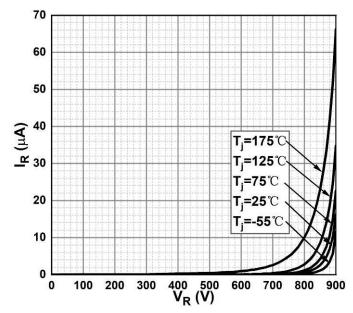
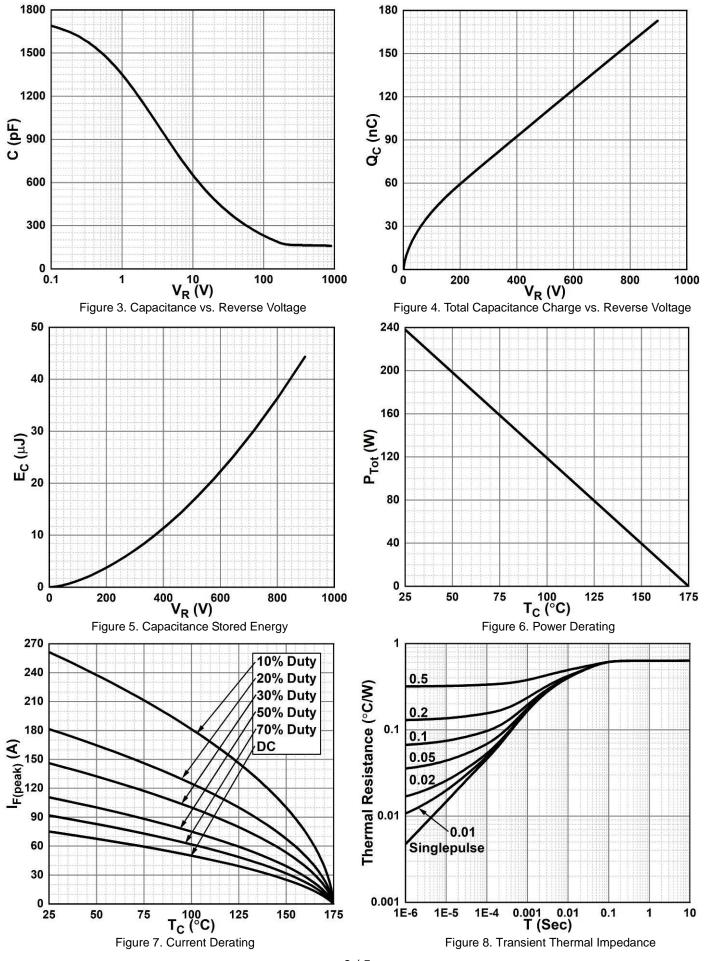


Figure 2. Reverse Characteristics







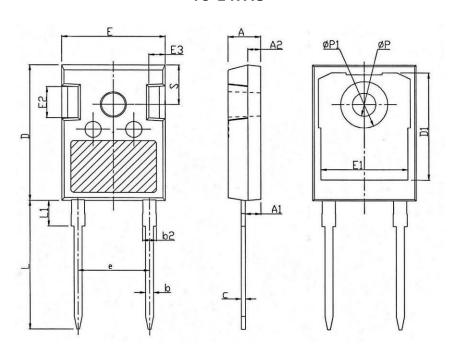






■Outline Dimensions





TO-247AC				
Dim	Min	Max		
Α	4.80	5.20		
A1	2.21	2.61		
A2	1.85	2.15		
b	1.11	1.36		
b2	1.91	2.21		
С	0.51	0.75		
D	20.70	21.30		
D1	16.25	16.85		
E	15.50	16.10		
E1	13.00	13.60		
E2	4.80	5.20		
E3	2.30	2.70		
е	10.88BSC			
L	19.62	20.22		
L1	-	4.30		
ΦР	3.40	3.80		
ФР1	-	7.30		
S	6.15BSC			



YJD106530NYG4



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